

INCHANGE SEMICONDUCTOR

Isc N-Channel MOSFET Transistor

TK72A12N1, ITK72A12N1

• FEATURES

- Low drain-source on-resistance: $R_{DS}(ON) = 4.5m\Omega$ (Vgs = 10 V)
- · Enhancement mode:

Vth = 2.0 to 4.0V (VDS = 10 V, ID=1.0mA)

- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

Switching Voltage Regulators

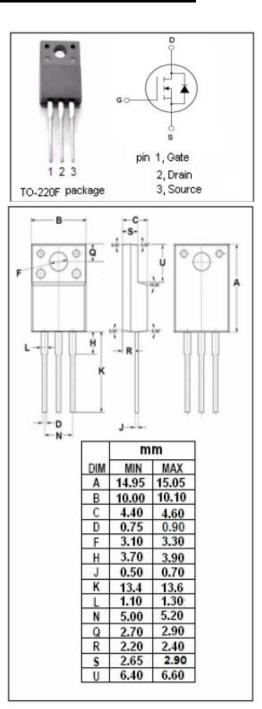
• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

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SYMBOL	PARAMETER	VALUE	UNIT					
V _{DSS}	Drain-Source Voltage	120	V					
V _{GS}	Gate-Source Voltage	±20	V					
ID	Drain Current-Continuous	72	А					
I _{DM}	Drain Current-Single Pulsed	355	А					
PD	Total Dissipation @T _c =25℃	45	W					
Tj	Max. Operating Junction Temperature	150	°C					
T _{stg}	Storage Temperature	-55~150	°C					

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	2.77	°C /W
Rth(ch-a)	Rth(ch-a) Channel-to-ambient thermal resistance		°C/W

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ELECTRICAL CHARACTERISTICS

 $T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	120			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = 10V; I _D =1.0mA	2.0		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =36A			4.5	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} = 0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 120V; V _{GS} = 0V			10	μA
VSDF	Diode forward voltage	I _{DR} =72A, V _{GS} = 0 V			1.2	V

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